BC818-40LT1

General Purpose Transistors

NPN Silicon

Features

• Pb-Free Package is Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	25	V
Collector – Base Voltage	V _{CBO}	30	V
Emitter-Base Voltage	V _{EBO}	5.0	V
Collector Current – Continuous	Ιc	500	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit		
Total Device Dissipation FR-5 Board, (Note 1) $T_A = 25^{\circ}C$ Derate above $25^{\circ}C$	P _D	225 1.8	mW mW/°C		
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	556	°C/W		
Total Device Dissipation Alumina Substrate, (Note 2) T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C		
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	417	°C/W		
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C		

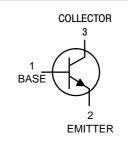
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in. 2. Alumina = $0.4 \times 0.3 \times 0.024$ in 99.5% alumina.



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SOT-23 **CASE 318 STYLE 6**

MARKING DIAGRAMS



6G = Specific Device Code

- M = Date Code*
 - = Pb-Free Package

(Note: Microdot may be in either location) *Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
BC818-40LT1	SOT-23	3000 / Tape & Reel
BC818-40LT1G	SOT-23 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

BC818-40LT1

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS					
Collector – Emitter Breakdown Voltage $(I_C = -10 \text{ mA})$	V _{(BR)CEO}	25	-	-	V
Collector – Emitter Breakdown Voltage $(V_{EB} = 0, I_C = -10 \ \mu A)$	V _{(BR)CES}	30	-	-	V
Emitter – Base Breakdown Voltage ($I_E = -1.0 \ \mu A$)	V _{(BR)EBO}	5.0	-	-	V
Collector Cutoff Current $(V_{CB} = 20 \text{ V})$ $(V_{CB} = 20 \text{ V}, T_A = 150^{\circ}\text{C})$	Ісво			100 5.0	nA μA
ON CHARACTERISTICS					•
DC Current Gain (I _C = 100 mA, V _{CE} = 1.0 V) (I _C = 500 mA, V _{CE} = 1.0 V)	h _{FE}	250 40	- -	600 -	-
Collector – Emitter Saturation Voltage $(I_C = 500 \text{ mA}, I_B = 50 \text{ mA})$	V _{CE(sat)}	-	-	0.7	V
Base – Emitter On Voltage $(I_C = 500 \text{ mA}, V_{CE} = 1.0 \text{ V})$	V _{BE(on)}	-	-	1.2	V
SMALL-SIGNAL CHARACTERISTICS					
Current-Gain – Bandwidth Product ($I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ Vdc}, f = 100 \text{ MHz}$)	f _T	100	-	-	MHz
Output Capacitance (V _{CB} = 10 V, f = 1.0 MHz)	C _{obo}	-	10	-	pF

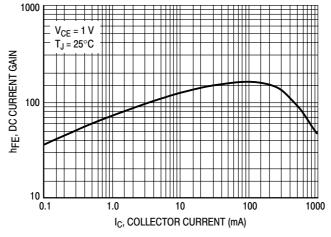
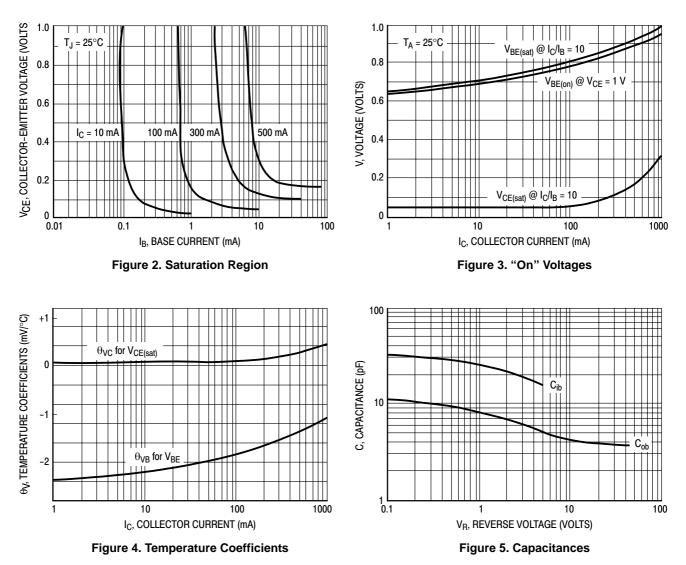
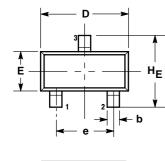


Figure 1. DC Current Gain



PACKAGE DIMENSIONS

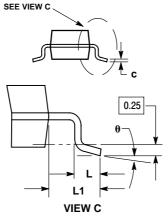
SOT-23 (TO-236) CASE 318-08 **ISSUE AN**



STYLE 6:

BASE PIN 1. 2 EMITTER 3.

COLLECTOR

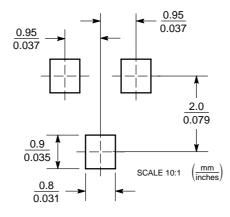


NOTES

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. CONTROLLING DIMENSION: INCH.
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD 3. THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 318-01 THRU -07 AND -09 OBSOLETE, NEW 4 STANDARD 318-08

	MILLIMETERS					
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.040	0.044
A1	0.01	0.06	0.10	0.001	0.002	0.004
b	0.37	0.44	0.50	0.015	0.018	0.020
с	0.09	0.13	0.18	0.003	0.005	0.007
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.081
L	0.10	0.20	0.30	0.004	0.008	0.012
L1	0.35	0.54	0.69	0.014	0.021	0.029
HE	2.10	2.40	2.64	0.083	0.094	0.104

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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